

Surface-mount Dual Circuit High-side Power Switch Array SDH04

Features

- Built-in diagnostic function to detect short and open circuiting of loads and output status signals
- Low saturation PNP transistor use
- Allows direct driving using LS-TTL and C-MOS logic levels
- Built-in overcurrent and thermal protection circuits
- Built-in protection against reverse connection of power supply
- $T_j = 150^\circ\text{C}$ guaranteed
- Surface-mount full-mold package

Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit	Conditions
Power supply voltage	V_B	-13 to +40	V	
Drive terminal applied voltage	V_D	-0.3 to V_B	V	
Input terminal voltage	V_{IN}	-0.3 to +7.0	V	
DIAG output applied voltage	V_{DIAG}	-0.3 to +7.0	V	
DIAG output source current	I_{DIAG}	3	mA	
Voltage across power supply and drive terminal	V_{B-D}	$V_B - 0.4$	V	
Output current	I_O	1.5	A	
Power dissipation	P_D	2.6	W	Without heatsink, all circuits operating
Junction temperature	T_j	-40 to +150	°C	
Operating temperature	T_{OP}	-40 to +100	°C	
Storage temperature	T_{STG}	-40 to +150	°C	

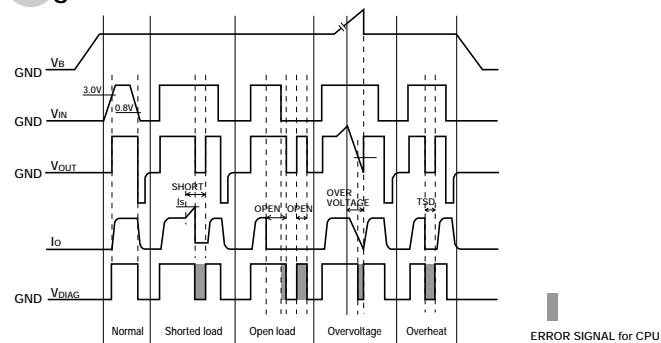
Electrical Characteristics

($V_{Bopr} = 14\text{V}$, $T_a = 25^\circ\text{C}$ unless otherwise specified)

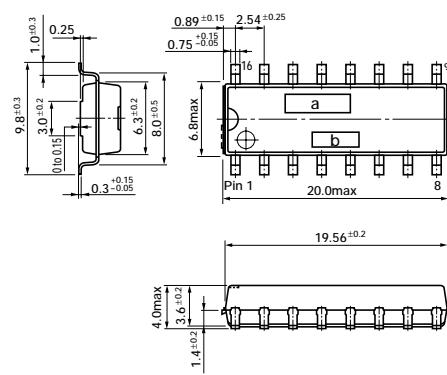
Parameter	Symbol	Ratings			Unit	Conditions
		min	typ	max		
Operating power supply voltage	V_{Bopr}	6.0		16	V	
Quiescent circuit current	I_Q		5	12	mA	Lo output
Threshold input voltage	V_{INth}	0.8		3.0	V	
Input current	Hi output I _{IN}			1.0	mA	$V_{IN} = 5\text{V}$
	Lo output I _{IN}	0		100	μA	$V_{IN} = 0\text{V}$
Saturation voltage of output transistor	$V_{CE(\text{sat})}$			0.5	V	$I_O \leq 1.0\text{A}$, $V_{Bopr} = 6$ to 16V
Output terminal sink current	$I_O(\text{sink})$			2.0	mA	$V_O = 0\text{V}$, $V_{IN} = 0\text{V}$
Saturation voltage of DIAG output	V_{DL}			0.3	V	$I_{DIAG} = 3\text{mA}$
Leak current of DIAG output	I_{DGH}			100	μA	$V_{DIAG} = 5\text{V}$
Open load detection resistor	R _{OPEN}	1		30	kΩ	
Overcurrent protection starting current	I _S	1.6			A	$V_O = V_{Bopr} - 1.9\text{V}$
Thermal protection starting temperature	T _{TSD}	150			°C	$V_{Bopr} \geq 6\text{V}$
Output transfer time	T _{ON}		8	30	μS	$I_O = 1\text{A}$
	T _{OFF}		15	30	μS	$I_O = 1\text{A}$
DIAG output transfer time	T _{PLH}		10	30	μS	$I_O = 1\text{A}$
	T _{PHL}		15	30	μS	$I_O = 1\text{A}$

Note: * The rule of protection against reverse connection of power supply is $V_B = -13\text{V}$, one minute (all terminals except, V_B and GND, are open).

Diagnostic Function

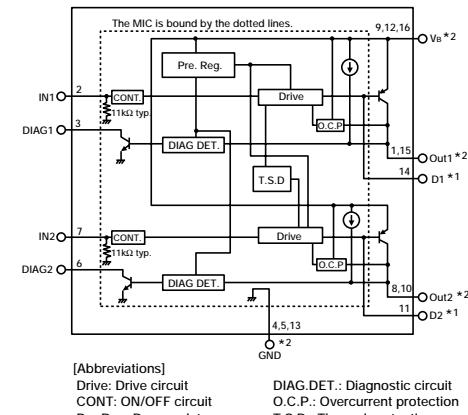


External Dimensions (unit: mm) SMD-16A



a: Type No.
b: Lot No.

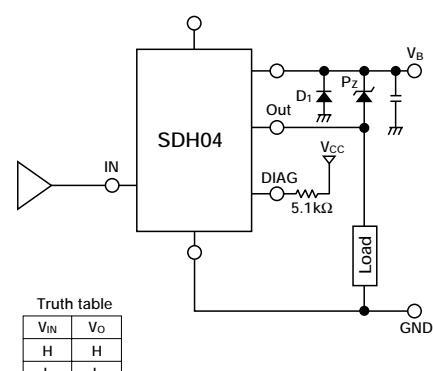
Equivalent Circuit Diagram



*1. The base terminal (D terminal) is connected to the output transistor base. It is also connected to the control monolithic IC. Do not, therefore, apply an external voltage in operation.

*2. SDH04 have two or three terminals of the same function (V_B , Out1, Out2, GND). The terminals of the same function must be shorted at a pattern near the product.

Standard Circuit Diagram



Note 1: A pull-down resistor (11 kΩ typ.) is connected to the IN terminal. V_{OUT} turns "L" when a high impedance is connected to the IN terminal in series.

